

TO-220 P MOS P-CHANNEL MOSFET in a TO-220 Plastic Package.

Low On-Resistance, High Current, High Speed switching, fast switching.

LED DC/DC DC/AC

/ Absolute Maximum Ratings($T_a=25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	-30	V
Drain Current	$I_D(T_c=25^\circ\text{C})$	-40	A
Drain Current	$I_D(T_c=100^\circ\text{C})$	-20	A
Pulsed Drain Current	I_{DM}	-120	A
Gate-Source Voltage	V_{GS}	± 25	V
Avalanche Current	I_{AS}	62	A
Total Power Dissipation	$P_D(T_c=25^\circ\text{C})$	80	W
Junction Temperature Range	T_j	-55 ~ 150	
Storage Temperature Range	T_{stg}	-55 ~ 150	
Thermal Resistance Junction-Ambient	R_{dJA}	65	/W
Thermal Resistance Junction-Case	R_{dJC}	3.72	/W

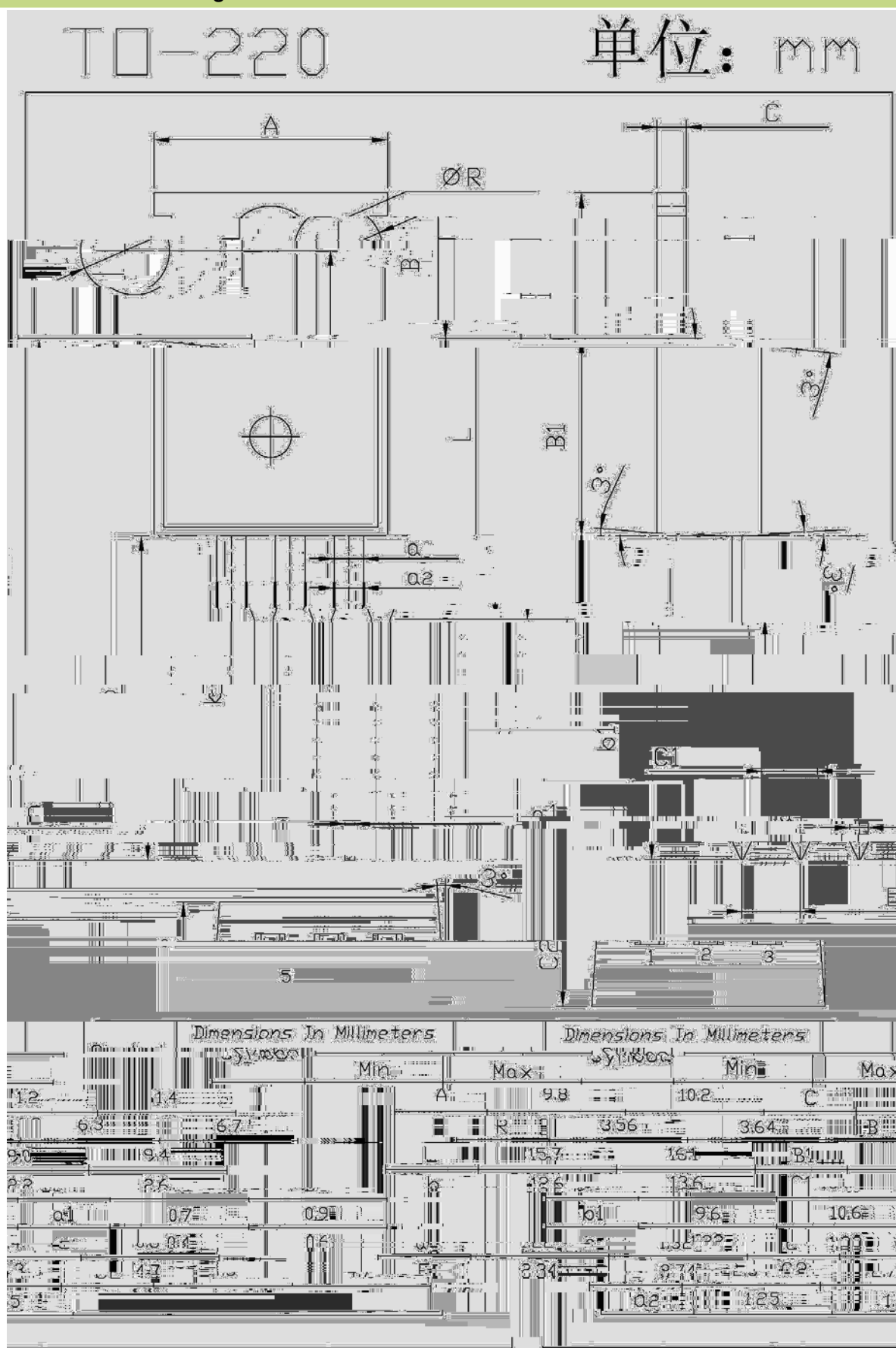
/ Electrical Characteristics($T_a=25^\circ\text{C}$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Zero Gate Voltage Drain Current	BV_{DSS}	$V_{GS}=0V$ $I_D=-250\mu A$	-30			V
BVDSS Temperature Coefficient	$\frac{BV_{DSS}}{T_j}$	$I_D=-1mA$ $T_a=25^\circ\text{C}$		-0.01		V/
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=-10V$ $I_D=-24A$			14	m Ω
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30V$ $V_{GS}=0V$			-1.0	μA
		$V_{DS}=-24V$ $T_c=150^\circ\text{C}$			-25	
Gate-Body Leakage Current Forward	I_{GSS}	$V_{GS}=\pm 25V$ $V_{DS}=0V$			± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=-250\mu A$	-1		-3	V
Forward Transconductance	g_{fs}	$V_{DS}=-10V$ $I_D=-24V$		35		S
Total Gate Charge	Q_g	$V_{DS}=-24A$ $I_D=-24V$ $V_{GS}=-4.5V$		30	55	nC
Gate-Source Charge	Q_{gs}			6		
Gate-Drain Charge	Q_{gd}			25		
Input Capacitance	C_{iss}	$V_{DS}=-25V$ $V_{GS}=0V$ $f=1.0MHz$		2200	3395	pF
Output Capacitance	C_{oss}			635		
Reverse Transfer Capacitance	C_{rss}			560		

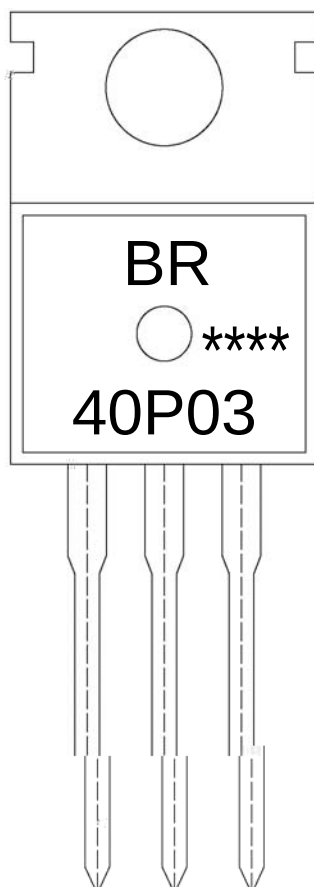
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-15V$ $I_D=-24A$ $R_G=3.3q$ $V_{GS}=-10V$ $R_D=0.63q$		10		ns
Rise Time	t_r			65		
Turn-Off Delay Time	$t_{d(off)}$			60		
Fall Time	t_f			100		
Reverse Recovery Time ²	t_{rr}	$V_{GS}=0V$ $I_S=-24A$ $di/dt=-100A/\mu s$		39		nC
Reverse Recovery Charge	Q_{rr}			38		
Diode Forward Voltage ²	V_{SD}	$V_{GS}=0V$ $I_S=-24A$ $T_J=25$			-1.2	V

/ Package Dimensions



/ Marking Instructions



BR

40P03

Note:

BR: Company Code

40P03: Product Type.

****: Lot No. Code, code change with Lot No.

